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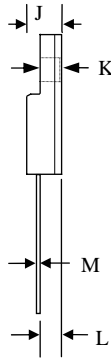
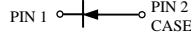
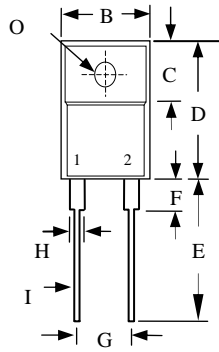
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20A SUPER FAST RECOVERY RECTIFIER

SFF200-03 THRU SFF200-06

CASE : ITO-220AC(SFF200-XX) , FULLY INSULATED PACKAGE



	MILLIMETERS	
	MIN	MAX
B	9.72	10.27
C	6.30	6.90
D	14.50	15.50
E	13.00	13.80
F	-	4.1
G	4.95	5.20
H	-	1.52
I	-	0.9
J	-	4.8
K	-	3.1
L	2.5	2.9
M	-	0.8
O	Ø 3.4	

FEATURES

- ULTRA FAST RECOVERY TIME
- LOW FORWARD VOLTAGE
- LOW THERMAL RESISTANCE
- HIGH CURRENT CAPABILITY
- HIGH VOLTAGE
- GLASS PASSIVATED CHIP JUNCTION

MECHANICAL DATA

- CASE: TRANSFER MOLDED
- TERMINAL: MIL-STD-202F METHOD 208
- POLARITY: AS MARKED
- EPOXY: UL94V-0 FLAME RETARDANT MOLDING COMPOUND
- WEIGHT 1.81 GRAMS

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS RATINGS AT 25°C AMBIENT TEMPERATURE UNLESS OTHERWISE SPECIFIED SINGLE PHASE, HALF WAVE, 60 HZ, RESISTIVE OR INDUCTIVE LOAD. FOR CAPACITIVE LOAD, DERATE CURRENT BY 20%.

RATINGS	SYMBOL	SFF200-03	SFF200-04	SFF200-05	SFF200-06	UNITS
MAXIMUM RECURRENT PEAK REVERSE VOLTAGE	V_{RRM}	300	400	500	600	V
MAXIMUM RMS VOLTAGE	V_{RMS}	210	280	350	420	V
MAXIMUM DC BLOCKING VOLTAGE	V_{DC}	300	400	500	600	V
MAXIMUM AVERAGE FORWARD RECTIFIED CURRENT SEE FIG.1	I_O	20.0				A
PEAK FORWARD SURGE CURRENT, 8.3ms SINGLE HALF SINE-WAVE SUPERIMPOSED ON RATED LOAD	I_{FSM}	250				A
TYPICAL JUNCTION CAPACITANCE (NOTE 1)	C_j	175				PF
TYPICAL THERMAL RESISTANCE (NOTE 2)	$R_{\theta jc}$	2.2				°C/W
STORAGE TEMPERATURE RANGE	T_{STG}	- 55 TO + 150				°C
OPERATING TEMPERATURE RANGE	T_{OP}	- 55 TO + 150				°C

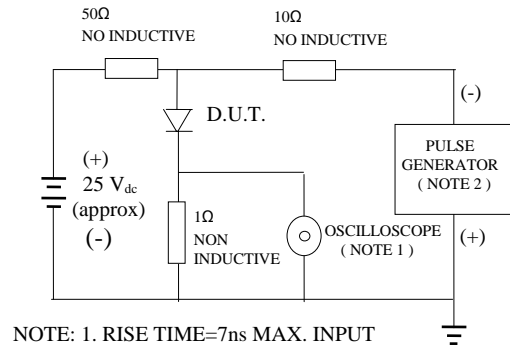
ELECTRICAL CHARACTERISTICS ($A_T T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

CHARACTERISTICS	SYMBOL	SFF200-03	SFF200-04	SFF200-05	SFF200-06	UNITS
MAXIMUM FORWARD VOLTAGE AT I_O PER LEG	V_F	1.30		1.70		V
MAXIMUM DC REVERSE CURRENT AT $T_A = 25^\circ\text{C}$	I_R	10				μA
MAXIMUM DC REVERSE CURRENT AT $T_A = 100^\circ\text{C}$	I_R	100				μA
MAXIMUM REVERSE RECOVERY TIME (NOTE 3)	T_{RR}	35				nS

- NOTES: 1. MEASURED AT 1 MHZ AND APPLIED REVERSE VOLTAGE OF 4.0 VOLTS
 2. THERMAL RESISTANCE JUNCTION TO CASE PER LEG MOUNTED ON HEAT SINK
 3. REVERSE RECOVERY TEST CONDITIONS: $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $I_{RR} = 0.25\text{A}$

RATINGS AND CHARACTERISTIC CURVE SFF200-03 THRU SFF200-06

FIG. 1 -TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTE: 1. RISE TIME=7ns MAX. INPUT IMPEDANCE=1 MOhms 22PF
2. RISE TIME =10 ns MAX. SOURCE IMPEDANCE=50 OHMS

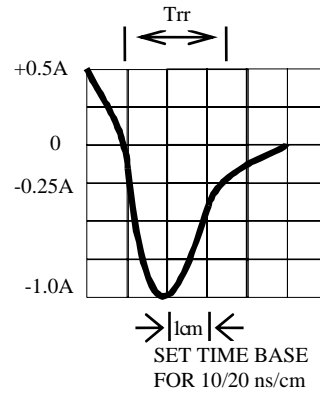


FIG. 2 -TYPICAL FORWARD CURRENT DERATING CURVE

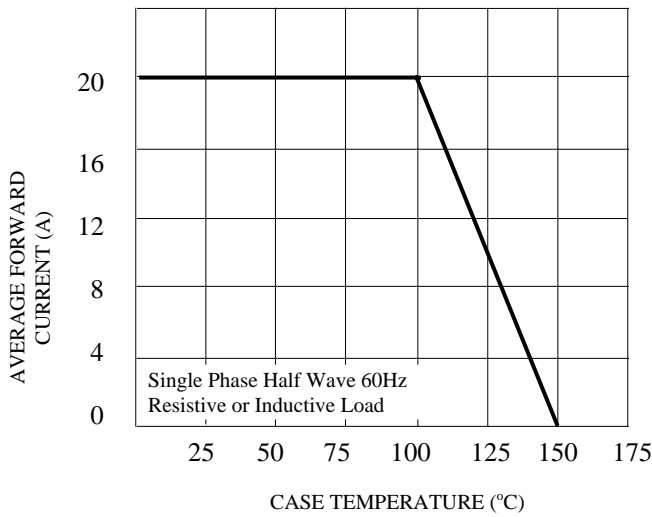


FIG. 3 -TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

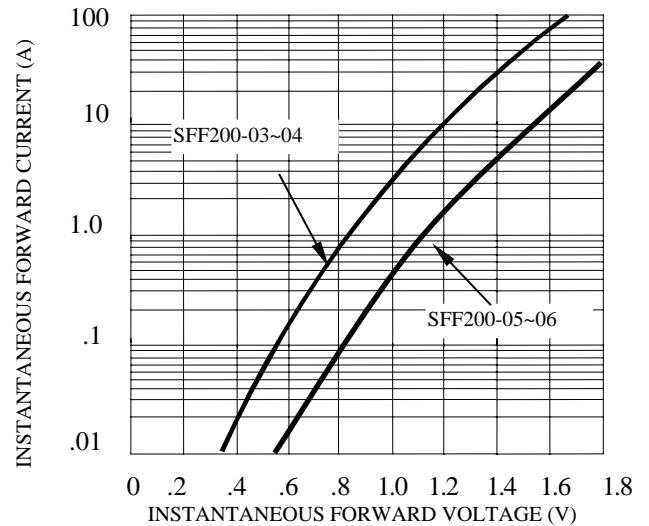


FIG. 4 -TYPICAL REVERSE CHARACTERISTICS

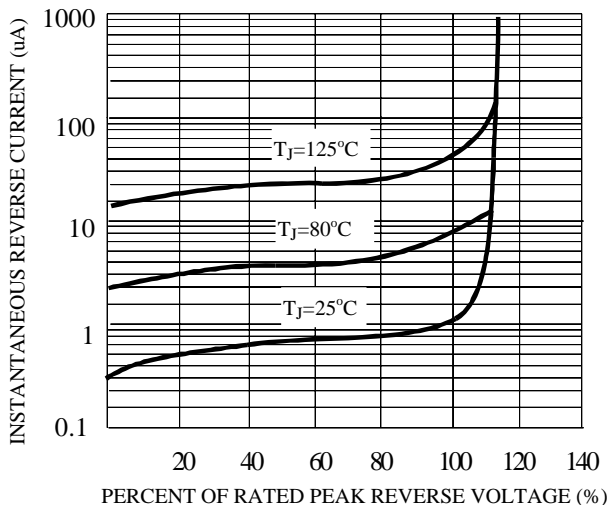


FIG. 5 -TYPICAL JUNCTION CAPACITANCE

